

2STBN15D100

Low voltage NPN power Darlington transistor

Features

- Good h_{FE} linearity
- High f_T frequency
- Monolithic Darlington configuration with integrated antiparallel collector-emitter diode

Application

■ Linear and switching industrial equipment

Description

The device is manufactured in planar technology with "base island" layout and monolithic Darlington configuration.

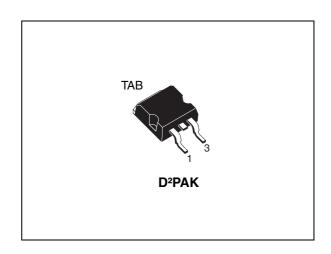


Figure 1. Internal schematic diagrams

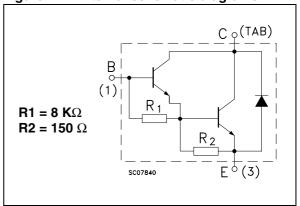


Table 1. Device summary

Order code	Marking	Package	Packaging
2STBN15D100	BN15D100	D ² PAK	Tube

Electrical ratings 2STBN15D100

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	100	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	100	V
V _{EBO}	Emitter-base voltage ($I_C = 0$)	5	V
I _C	Collector current	12	Α
I _{CM}	Collector peak current	15	Α
I _B	Base current	0.2	Α
P _{TOT}	Total dissipation at T _{case} = 25 °C	70	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max.	1.8	°C/W

2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C; \text{ unless otherwise specified})$

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 100 V		1	100	μА
I _{CEO}	Collector cut-off current (I _B = 0)	V _{CE} = 50 V		ı	100	μА
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5 V	0.12	-	2	mA
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C = 100 mA	100	1		V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_C = 0.5 \text{ A}$ $I_B = 1 \text{ mA}$ $I_C = 4 \text{ A}$ $I_B = 4 \text{ mA}$		1	1.5 1.3	V V
V _{BE(on)} ⁽¹⁾	Base-emitter on voltage	$I_C = 3 A$ $V_{CE} = 3 V$		1	2.5	V
h _{FE} ⁽¹⁾	DC current gain	$I_C = 3 A$ $V_{CE} = 3 V$	750	-		
V _F	Diode forward voltage	I _F = 3 A		-	2.5	V

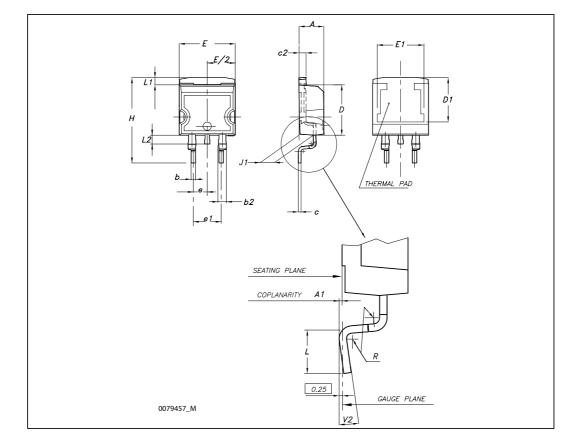
^{1.} Pulse test: pulse duration ≤300 µs, duty cycle ≤2 %.

3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

D²PAK (TO-263) mechanical data

Dim		mm			inch	
	Min	Тур	Max	Min	Тур	Max
A	4.40		4.60	0.173		0.181
A1	0.03		0.23	0.001		0.009
b	0.70		0.93	0.027		0.037
b2	1.14		1.70	0.045		0.067
С	0.45		0.60	0.017		0.024
c2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1	7.50			0.295		
E	10		10.40	0.394		0.409
E1	8.50			0.334		
е		2.54			0.1	
e1	4.88		5.28	0.192		0.208
Н	15		15.85	0.590		0.624
J1	2.49		2.69	0.099		0.106
L	2.29		2.79	0.090		0.110
L1	1.27		1.40	0.05		0.055
L2	1.30		1.75	0.051		0.069
R		0.4			0.016	
V2	0°		8°	0°		8°



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Revision history 2STBN15D100

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
01-Sep-2009	1	First release.

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